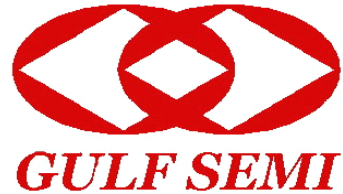


SSF5JG THRU SSF5MG

ULTRAFAST EFFICIENT GLASS PASSIVATED RECTIFIER

VOLTAGE: 600 TO 1000V

CURRENT: 5.0A



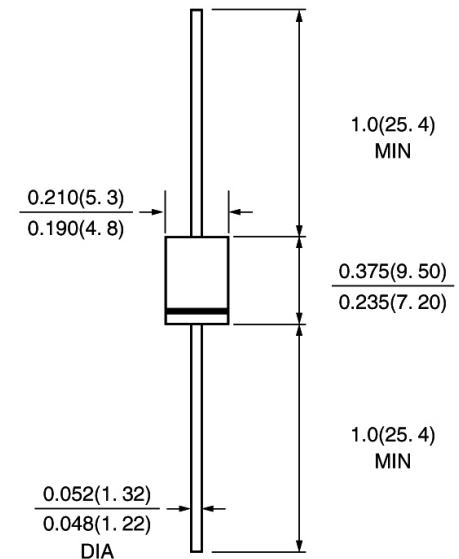
FEATURE

Low power loss
High surge capability
Ultra-fast recovery time for high efficiency
Glass passivated chip junction
High temperature soldering guaranteed
250°C/10sec/0.375"lead length at 5 lbs tension

MECHANICAL DATA

Terminal: Plated axial leads solderable per
MIL-STD 202E, method 208C
Case: Molded with UL-94 Class V-0 recognized Flame
Retardant Epoxy
Polarity: color band denotes cathode
Mounting position: any

DO-201AD



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half -wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	SYMBOL	SSF5JG	SSF5KG	SSF5MG	units
Maximum Recurrent Peak Reverse Voltage	V _{rrm}	600	800	1000	V
Maximum RMS Voltage	V _{rms}	420	560	700	V
Maximum DC blocking Voltage	V _{dc}	600	800	1000	V
Maximum Average Forward Rectified Current 3/8"lead length at T _a =55°C	I _{f(av)}	5.0			A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{fsm}	150.0			A
Maximum Forward Voltage at Forward current 5A Peak	V _f	1.70			V
Maximum DC Reverse Current T _a =25°C at rated DC blocking voltage T _a =125°C	I _r	10.0 100.0			μA
Maximum Reverse Recovery Time (Note 1)	T _{rr}	35			nS
Typical Junction Capacitance (Note 2)	C _j	65			pF
Storage and Operating Junction Temperature	T _{stg} , T _j	-55 to +150			°C

Note:

1. Reverse Recovery Condition I_f =0.5A, I_r =1.0A, I_{rr} =0.25A
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V_{dc}

RATINGS AND CHARACTERISTIC CURVES SSF5JG THRU SSF5MG

FIG.1- FORWARD CURRENT DERATING CURVE

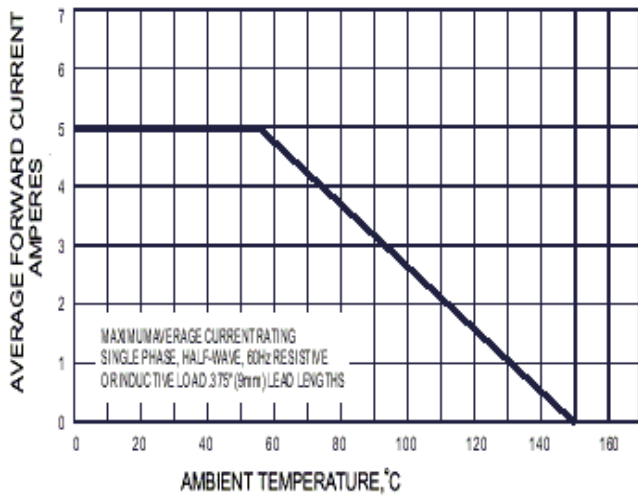


FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

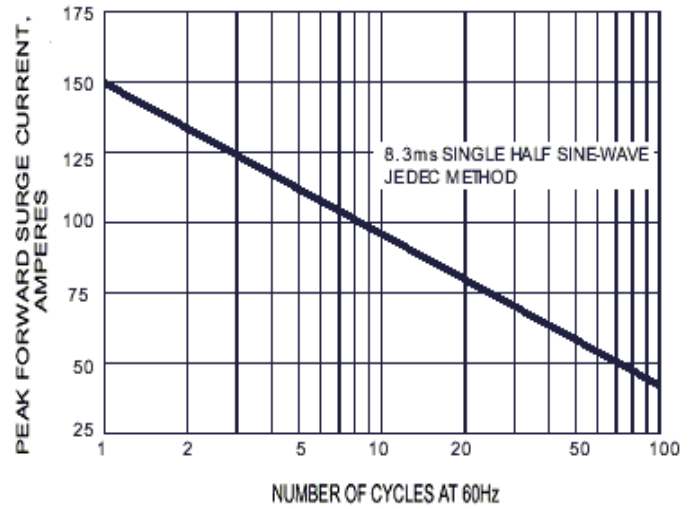


FIG.3- TYPICAL REVERSE LEAKAGE CHARACTERISTICS

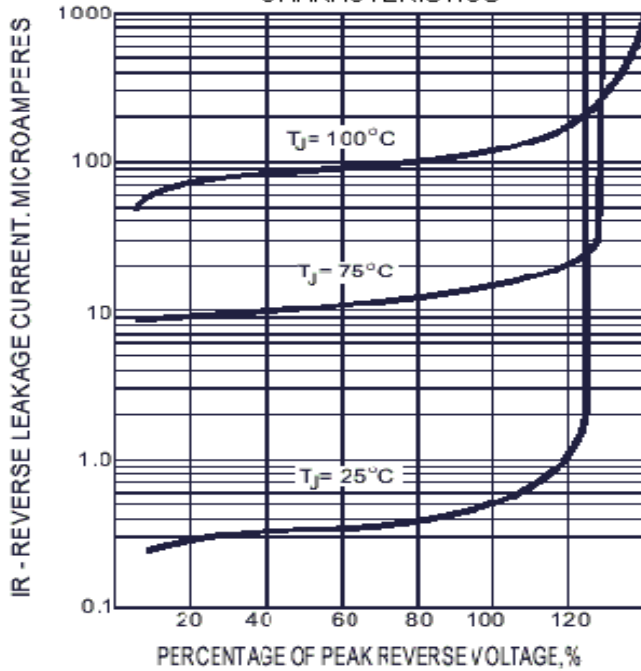


FIG.4- TYPICAL FORWARD CHARACTERISTICS

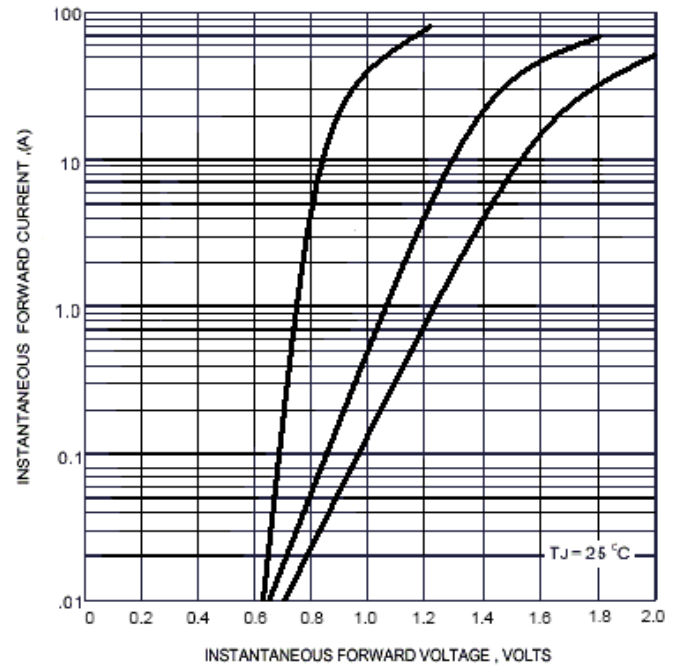


FIG.5- TYPICAL JUNCTION CAPACITANCE

